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D. Chen, J. Chen and D. Sarid, Si–C_{60}–Si(111)-(7 × 7) interactions: a scanning tunneling microscopy study 321 (1994) 190

H.W. Yeom, T. Abukawa, Y. Takakuwa, M. Nakamura, M. Kimura, A. Kakizaki and S. Kono, Surface electronic structure of single-domain Si(001)2 × 2-Al: an angle-resolved photoelectron spectroscopy study using synchrotron radiation 321 (1994) L177

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A. Nishiyama, G. ter Horst, M. Lohmeier, A.M. Molenbroek and J.W.M. Frenken, Structure analysis of HF-treated Si(111):H surface with medium-energy ion scattering 321 (1994) 261

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R. Ishigami, J. Yuhara and K. Morita, The change of coverage and structure of the Si(111)-$\sqrt{3} \times \sqrt{3}$-Ag surface by isothermal annealing 321 (1994) 100

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Vanadium

J.G. Chen, C.M. Kim, B. Frühberger, B.D. DeVries and M.S. Touvelle, A NEXAFS determination of the oxidation state of vanadium carbide on V(110): observation of charge transfer from vanadium to carbon 321 (1994) 145

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R. Kubiak, H. Morgner and O. Rakhovskaya, Study of NiO/Ni(100) structural changes under the influence of ion irradiation at different temperatures 321 (1994) 229

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J. Stober, B. Eisenhut, G. Rangelov and Th. Fauster, Initial stages of the thermal nitridation of the Si(100) surface with NH_3 and NO: a surface sensitive study of Si 2p core-level shifts 321 (1994) 111

Tellurides

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Titanium oxide

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V. Matolin, T. Gronych and M. Gillet, The RHEED and ESDIAD methods as a probe of supported particle structure and morphology: Pd on KCl 321 (1994) L143

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H. Zillgen, B. Feldmann and M. Wuttig, Structural and magnetic properties of ultrathin Fe films deposited at low temperature on Cu(100) 321 (1994) 32

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H.W. Yeom, T. Abukawa, Y. Takakuwa, M. Nakamura, M. Kimura, A. Kakizaki and S. Kono, Surface electronic structure of single-domain Si(001)2 × 2-Al: an angle-resolved photoelectron spectroscopy study using synchrotron radiation 321 (1994) L177

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A. Klein, C. Pettenkofer, W. Jaegermann, M. Lux-Steiner and E. Bucher, A photoemission study of barrier and transport properties of the interfaces of Au and Cu with WSe_2(0001) surfaces 321 (1994) 19

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N.J. Tao and Z. Shi, Real-time STM/AFM study of electron transfer reactions of an organic molecule: xanthine at the graphite–water interface 321 (1994) L149

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M. Sambi, L. Zaratin, G. Granozzi, G.A. Rizzi, E. Tondello and A. Santaniello, Angle-scanned photoelectron diffraction chemisorption study of c(2 × 2)-O on Ni(1 ML)/Cu(100) 321 (1994) L214

C. Nagl, O. Haller, E. Platzgummer, M. Schmid and P. Varga, Submonolayer growth of Pb on Cu(111): surface alloying and dealloying 321 (1994) 237

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Given below is a listing of keywords for the Subject and Materials Indexes used by Surface Science. The Subject index is divided into three classes: Theoretical Methods, Experimental Methods, and Phenomena. Please indicate below your abstract at least one keyword from as many of the three classes as appropriate to describe the contents of your manuscript. (You may also tick the appropriate box and include this list with your manuscript.) Occasionally it will not be possible to include a keyword from all three classes, e.g., a general theory manuscript will not exhibit a keyword from the Experimental Methods class. In such a case, omit the entry from the inapplicable class. Also, if appropriate, please select a keyword from one of the three classes of the Materials Index, i.e., Elemental and Chemical Identity, Physical State, and Electrical and Magnetic Behavior. You may use multiple keywords in the above mentioned six classes up to a maximum of eight in total. For example, many experimental papers will be characterized by more than one keyword in the Experimental Methods class of the Subject Index as well as by several keywords from the Materials Index.

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- ☐ Electron density, excitation spectra calculations
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- ☐ Equilibrium thermodynamics and statistical mechanics
- ☐ Green's function methods
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- ☐ Auger electron spectroscopy
- ☐ Chemical vapor deposition
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  - ☐ *Electron stimulated desorption (ESD)*
  - ☐ *Photon stimulated desorption (PSD)*
  - ☐ *Surface photochemistry*
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- ☐ Electrochemical methods
- ☐ Electron emission measurements
  - ☐ *Exoelectron emission*
  - ☐ *Field emission*
  - ☐ *Photoemission (total yield)*
  - ☐ *Secondary electron emission*
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  - ☐ *Low energy electron diffraction (LEED)*
  - ☐ *Photoelectron diffraction*
  - ☐ *Photoelectron holography*
  - ☐ *Reflection high-energy electron diffraction (RHEED)*
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- ☐ Electron–solid scattering and transmission – inelastic
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- ☐ Molecule–solid scattering and diffraction – inelastic
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  - ☐ *X-ray photoelectron spectroscopy*
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  - ☐ *Plasmons*
  - ☐ *Polaritons*
- ☐ Thermal desorption
- ☐ Thermionic emission
- ☐ Tribology
- ☐ Tunneling
- ☐ Vibrations of adsorbed molecules
- ☐ Wetting

Materials index

ELEMENTAL AND CHEMICAL IDENTITY
(Include each component of an interface or multilayer structure as a separate category. Add your own specific elemental or chemical label if a suitable entry is not on the list.)

Elements

- ☐ Alkali metals
- ☐ Alkaline earth metals
- ☐ Aluminum
- ☐ Antimony
- ☐ Arsenic
- ☐ Bismuth
- ☐ Boron
- ☐ Bromine
- ☐ Cadmium
- ☐ Carbon
- ☐ Cerium
- ☐ Chalcogens
- ☐ Chlorine
- ☐ Chromium
- ☐ Cobalt
- ☐ Copper
- ☐ Diamond
- ☐ Gallium
- ☐ Germanium
- ☐ Gold
- ☐ Graphite
- ☐ Hafnium
- ☐ Hydrogen
- ☐ Indium
- ☐ Iodine
- ☐ Iridium
- ☐ Iron
- ☐ Lanthanides
- ☐ Lead
- ☐ Manganese
- ☐ Mercury
- ☐ Molybdenum
- ☐ Nickel
- ☐ Niobium
- ☐ Nitrogen
- ☐ Noble gases
- ☐ Osmium
- ☐ Palladium
- ☐ Phosphorus
- ☐ Platinum
- ☐ Rhenium
- ☐ Rhodium
- ☐ Ruthenium
- ☐ Scandium
- ☐ Silicon
- ☐ Silver
- ☐ Tantalum
- ☐ Technetium
- ☐ Thallium
- ☐ Thorium
- ☐ Tin
- ☐ Titanium
- ☐ Tungsten
- ☐ Uranium
- ☐ Vanadium
- ☐ Ytterbium
- ☐ Yttrium
- ☐ Zinc
- ☐ Zirconium
- ☐ Other .....*

Compounds (non-molecular solids)

- ☐ Alkali halides
- ☐ Alloys
- ☐ Aluminum oxide
- ☐ Barium oxide
- ☐ Biological compounds
- ☐ Borides
- ☐ Boron nitride
- ☐ Cadmium selenide
- ☐ Cadmium sulphide
- ☐ Cadmium telluride
- ☐ Carbides
- ☐ Cobalt oxides
- ☐ Copper oxides
- ☐ Gallium antimonide
- ☐ Gallium arsenide
- ☐ Gallium nitride
- ☐ Gallium phosphide
- ☐ Gallium selenide
- ☐ Halides
- ☐ Hydrides
- ☐ Indium antimonide
- ☐ Indium arsenide
- ☐ Indium oxides
- ☐ Indium phosphide
- ☐ Inorganic compounds
- ☐ Iron oxide
- ☐ Lead telluride
- ☐ Magnesium oxides
- ☐ Mercury telluride
- ☐ Mica
- ☐ Molybdenum oxides
- ☐ Nickel carbide
- ☐ Nickel oxides
- ☐ Nickel sulphide
- ☐ Nitrides
- ☐ Silicides
- ☐ Silicon carbide
- ☐ Silicon–germanium
- ☐ Silicon nitride
- ☐ Silicon oxides
- ☐ Steel
- ☐ Sulphides
- ☐ Tin oxides
- ☐ Tin telluride
- ☐ Titanium carbide
- ☐ Titanium oxide
- ☐ Tungsten oxide
- ☐ Uranium oxide
- ☐ Vanadium oxide
- ☐ Zeolites
- ☐ Zinc oxide
- ☐ Zinc selenide
- ☐ Other .....*

Molecules

- ☐ Alcohols
- ☐ Aldehydes
- ☐ Alkanes
- ☐ Alkenes
- ☐ Alkynes
- ☐ Ammonia
- ☐ Aromatics
- ☐ Biological molecules – nucleic acids
- ☐ Biological molecules – proteins
- ☐ Biological molecules – other .....*
- ☐ Carbon dioxide
- ☐ Carbon monoxide
- ☐ Carboxylic acid
- ☐ Cyanogen
- ☐ Deuterium
- ☐ Esters
- ☐ Ethers
- ☐ Fullerenes
- ☐ Halogens
- ☐ Hydrogen
- ☐ Hydrogen cyanide
- ☐ Hydrogen sulphide
- ☐ Ketones
- ☐ Nitrogen
- ☐ Nitrogen oxides
- ☐ Oxygen
- ☐ Ozone
- ☐ Phosphine
- ☐ Silane
- ☐ Sulphur dioxide
- ☐ Sulphur hexafluoride
- ☐ Water
- ☐ Other .....

PHYSICAL STATE

Surfaces

- ☐ Amorphous surfaces
- ☐ Dendritic and/or fractile surfaces
- ☐ Glass surfaces
- ☐ Liquid surfaces
- ☐ Polycrystalline surfaces

- ☐ Single crystal surfaces
  - ☐ *Low index single crystal surfaces*
  - ☐ *Stepped single crystal surfaces*
  - ☐ *Vicinal single crystal surfaces*
- ☐ Surface defects
- ☐ Whiskers

Interfaces
- ☐ Crystalline–amorphous interfaces
- ☐ Crystalline–glass interfaces
- ☐ Grain boundaries
- ☐ Liquid–gas interfaces
- ☐ Single crystal epitaxy
- ☐ Solid–liquid interfaces
- ☐ Solid–gas interfaces

Heterostructures
- ☐ Heterojunctions
- ☐ Quantum wells
- ☐ Superlattices

Non-epitaxial thin film structures
- ☐ Amorphous thin films
- ☐ Ceramic thin films
- ☐ Glassy thin films
- ☐ Polycrystalline thin films

☐ **Adatoms**

☐ **Clusters**

Particulate composites
- ☐ Blacks
- ☐ Ceramics
- ☐ Powders

☐ **Coatings**

☐ **Porous solids**

ELECTRICAL AND MAGNETIC BEHAVIOR

Surfaces and/or films
- ☐ Insulating films
- ☐ Insulating surfaces
- ☐ Magnetic films
- ☐ Magnetic surfaces
- ☐ Metallic films
- ☐ Metallic surfaces
- ☐ Semiconducting films
- ☐ Semiconducting surfaces
- ☐ Superconducting films
- ☐ Superconducting surfaces

Interfaces
- ☐ Magnetic interfaces
- ☐ Metal–electrolyte interfaces
- ☐ Metal–insulator interfaces
- ☐ Metal–metal interfaces
- ☐ Metal–semiconductor interfaces
- ☐ Schottky barrier
- ☐ Semiconductor–electrolyte interfaces
- ☐ Semiconductor–insulator interfaces
- ☐ Semiconductor–semiconductor interfaces
- ☐ Semiconductor–superconductor interfaces
- ☐ Other interfaces .....*

Heterostructures and thin film structures
- ☐ Metal–metal magnetic heterostructures
- ☐ Metal–metal magnetic thin film structures
- ☐ Metal–metal nonmagnetic heterostructures
- ☐ Metal–metal nonmagnetic thin film structures
- ☐ Metal–oxide–semiconductor (MOS) structures
- ☐ Metal–semiconductor magnetic heterostructures
- ☐ Metal–semiconductor magnetic thin film structures
- ☐ Metal–semiconductor nonmagnetic heterostructures
- ☐ Metal–semiconductor nonmagnetic thin film structures
- ☐ Semiconductor–semiconductor heterostructures
- ☐ Semiconductor–semiconductor thin film structures
- ☐ Superconductor–semiconductor heterostructures
- ☐ Superconductor–semiconductor thin film structures
- ☐ Other heterostructures .....*
- ☐ Other thin film structures .....*

☐ **Contacts**

*Please, fill in necessary new Materials Index Keyword. If the new keyword is indicated on the manuscript, please, make clear to which subcategory it belongs.